


International
IR Rectifier

MB High Voltage SERIES

SINGLE PHASE BRIDGE

Power Modules

Features

- Universal, 3 way terminals:
push-on, wrap around or solder
- High thermal conductivity package,
electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- UL E 62320 approved 
- Nickel plated terminals solderable as per MIL-STD-202 Method
208; solder: Sn/Pb (60/40); solder temperature: 235-260°C
max. time: 8-10 secs

25 A
35 A

Description

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

Major Ratings and Characteristics

Parameters	26MB-A	36MB-A	Units
I_O	25	35	A
@ T_C	70	55	°C
I_{FSM} @ 50Hz	400	475	A
@ 60Hz	420	500	A
I^2t @ 50Hz	790	1130	A ² s
@ 60Hz	725	1030	A ² s
V_{RRM} range	1400 to 1600		V
T_J	-55 to 150		°C

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ T_J max. mA
26MB..A	140	1400	1500	2
36MB..A	160	1600	1700	

Forward Conduction

Parameters	26MB-A	36MB-A	Units	Conditions
I_O Maximum DC output current @ Case temperature	25	35	A	Resistive or inductive load
	20	28	A	Capacitive load
	65	60	°C	
I_{FSM} Maximum peak, one-cycle non-repetitive forward current	400	475	A	t = 10ms No voltage reappplied
	420	500		t = 8.3ms
	335	400		t = 10ms 100% V_{RRM} reappplied
	350	420		t = 8.3ms
I^2t Maximum I^2t for fusing	790	1130	A ² s	t = 10ms No voltage reappplied
	725	1030		t = 8.3ms
	560	800		t = 10ms 100% V_{RRM} reappplied
	512	730		t = 8.3ms
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	5.6	11.3	KA ² √s	I^2t for time $t_x = I^2\sqrt{t_x} \sqrt{t_x}$; $0.1 \leq t_x \leq 10ms, V_{RRM} = 0V$
$V_{F(TO)1}$ Low-level of threshold voltage	0.70	0.74	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, @ T_J max.
$V_{F(TO)2}$ High-level of threshold voltage	0.75	0.79	V	$(I > \pi \times I_{F(AV)})$, @ T_J max.
r_{t1} Low-level forward slope resistance	7.0	5.5	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, @ T_J max.
r_{t2} High-level forward slope resistance	6.4	5.2	mΩ	$(I > \pi \times I_{F(AV)})$, @ T_J max.
V_{FM} Maximum forward voltage drop	1.25	1.3	V	$T_J = 25^\circ C, I_{FM} = 40A_{PK}(26MB)$ $T_J = 25^\circ C, I_{FM} = 55A_{PK}(36MB)$ tp = 400μs
I_{RRM} Max. DC reverse current	10	10	μA	$T_J = 25^\circ C$, per diode at V_{RRM}
V_{INS} RMS isolation voltage base plate	2700	2700	V	f = 50 Hz, t = 1s

Thermal and Mechanical Specifications

Parameters	26MB-A	36MB-A	Units	Conditions
T_J Junction temperature range	-55 to 150 °C			
T_{stg} Storage temperature range	-55 to 150 °C			
R_{thJC} Max. thermal resistance junction to case	1.7	1.35	K/W	Per bridge
R_{thCS} Max. thermal resistance, case to heatsink	0.2		K/W	Mounting surface, smooth, flat and greased
wt Approximate weight	20		g	
T Mounting Torque ± 10%	2.0		Nm	Bridge to heatsink

Ordering Information Table

Device Code			
36	MB	160	A
①	②	③	④

<p>1 -</p> <p>2 -</p> <p>3 -</p> <p>4 -</p>	<p>Current rating code: _____</p> <p>Circuit configuration: MB = Single phase european coding</p> <p>Voltage code: MB series = code x 10 = V_{RRM}</p> <p>Diode bridge rectifier: A = 26MB, 36MB Series</p>	<p>26 = 25A (Avg)</p> <p>36 = 35A (Avg)</p>
---	--	---

Outline Table

0.8 (.03) 6.3 (.25)

10.5 (.41) 20.3 (.80)

21.5 (0.85) 9.5 (0.37) 28.5 (1.12) 5 (0.2) 12.7 (0.5)

Suggested plugging force:
200 N max; axially applied to faston terminals

Not To Scale

All dimensions in millimetres (inches)

MB High Voltage Series

Bulletin I27177 03/03

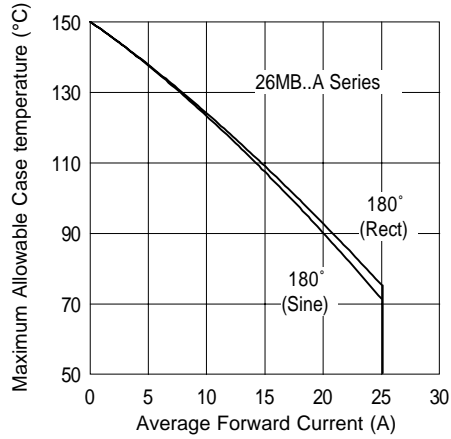


Fig. 1 - Current Ratings Characteristics

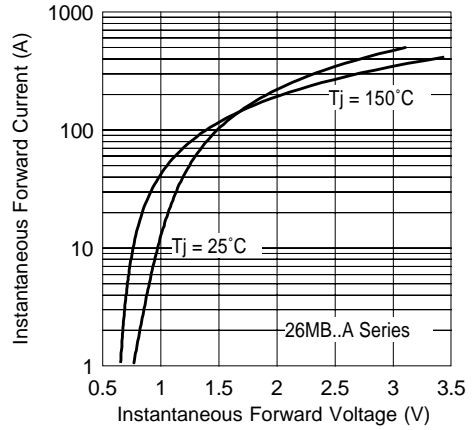


Fig. 2 - Forward Voltage Drop Characteristics
Maximum Allowable Ambient Te

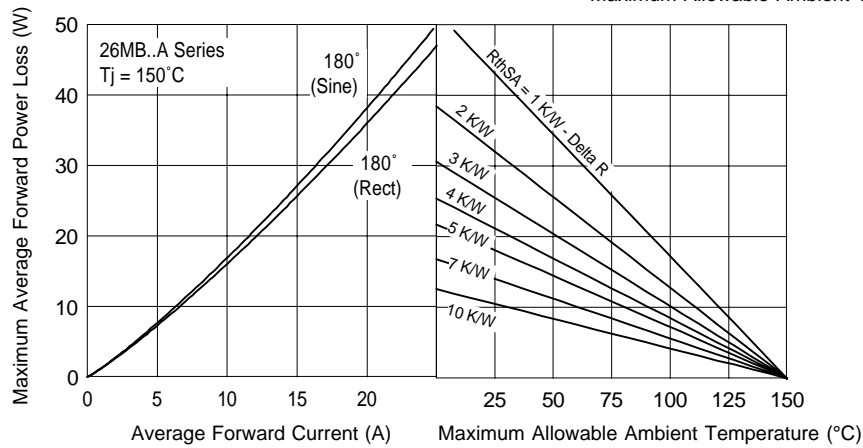


Fig. 3 - Total Power Loss Characteristics

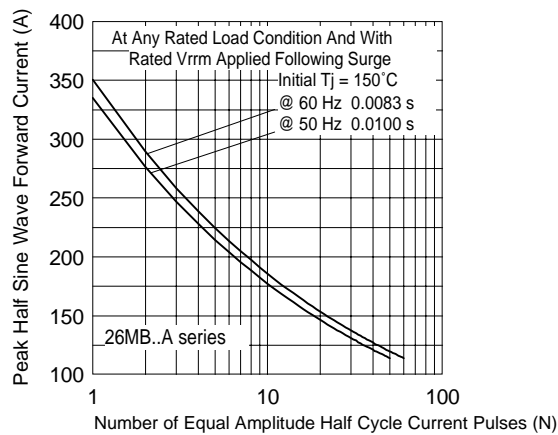


Fig. 4 - Maximum Non-Repetitive Surge Current

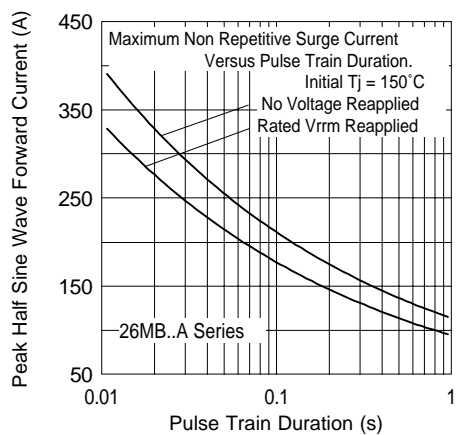


Fig. 5 - Maximum Non-Repetitive Surge Current

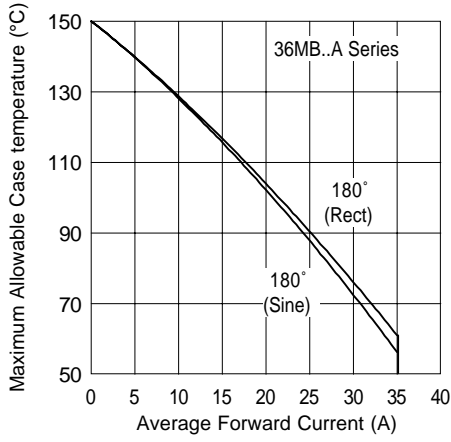


Fig. 6 - Current Ratings Characteristics

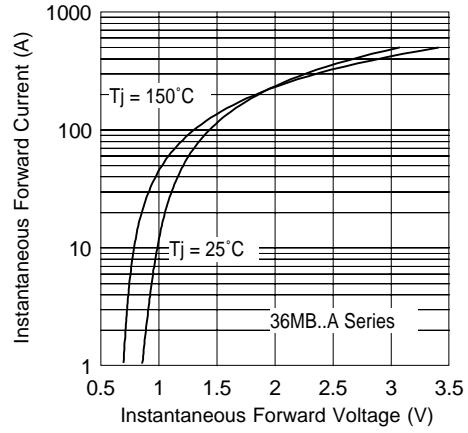


Fig. 7 - Forward Voltage Drop Characteristics
Maximum Allowable Ambient Te

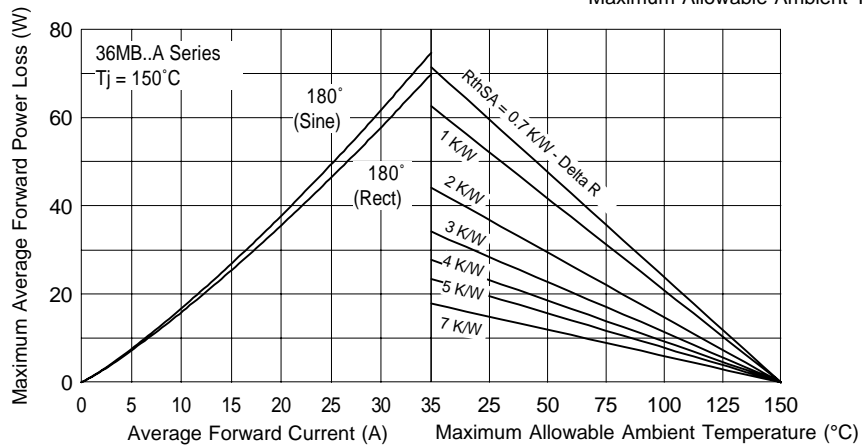


Fig. 3 - Total Power Loss Characteristics

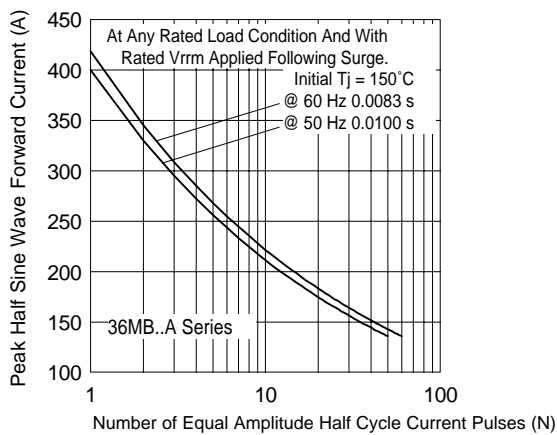


Fig. 9 - Maximum Non-Repetitive Surge Current

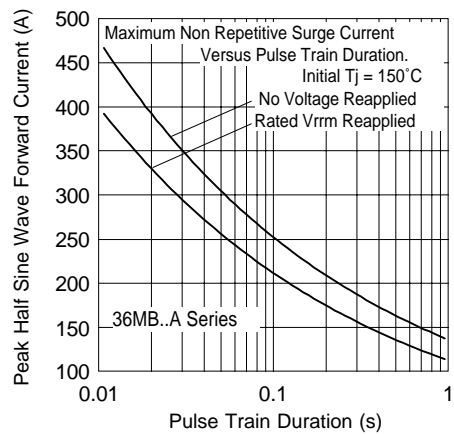


Fig. 10 - Maximum Non-Repetitive Surge Current

MB High Voltage Series

Bulletin I27177 03/03

International
IOR Rectifier

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial and Consumer Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/03